Monolithic Amplifier

DC-8 GHz

Product Features

- DC-8 GHz
- Single voltage supply
- Internally matched to 50 ohms
- Unconditionally stable
- · Low performance variation over temperature
- Transient protected
- Aqueous washable
- Protected by US Patent 6,943,629

Typical Applications

- Cellular/ PCS/ 3G Base Station
- CATV, Cable Modem & DBS
- Fixed Wireless & WLAN
- Microwave Radio & Test Equipment



Generic photo used for illustration purposes only

ERA-1+

CASE STYLE: VV105

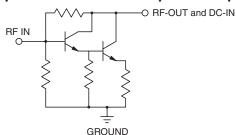
+RoHS Compliant

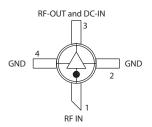
The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

General Description

ERA-1+ (RoHS compliant) is a wideband amplifier offering high dynamic range. It has repeatable performance from lot to lot. It is enclosed in a Micro-X package. ERA-1+ uses Darlington configuration and is fabricated using InGaP HBT technology. Expected MTTF is 6300 years at 85°C case temperature.

simplified schematic and pin description





Function	Pin Number	Description
RF IN	1	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
RF-OUT and DC-IN 3		RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit".
GND	2,4	Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance.

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Electrical Specifications at 25°C and 40mA, unless noted

Parameter		Min.	Тур.	Max.	Units	Cpk
Frequency Range*		DC		8	GHz	
Gain	f=0.1 GHz	11.4	12.3	12.9	dB	≥ 1.5
	f=1 GHz	_	12.1	_		
	f=2 GHz	10.3	11.8	12.9		
	f=3 GHz	_	10.9	_		
	f=4 GHz	_	9.7	_		
	f=6 GHz	_	7.9	_		
	f=8 GHz		8.2	_	1	
Magnitude of Gain Variation versus Temperature	f=0.1 GHz	_	.0012	.0025	dB/°C	
(values are negative)	f=1 GHz	_	.0015	.003		
	f=2 GHz	_	.0017	.0035		
	f=3 GHz	_	.002	.004		
	f=4 GHz	_	.002	.004		
	f=6 GHz	_	.0022	.005		
Land Debug Lees	f=8 GHz f=0.1 GHz		.0019 30	.005	dB	
Input Return Loss	f=2 GHz		25		ub ub	
	f=3 GHz		23			
	f=4 GHz		23			
	f=6 GHz		18			
	f=8 GHz		16			
Output Return Loss	f=0.1 GHz		26		dB	
Output Hetuiii Loss	f=2 GHz		21		ub	
	f=3 GHz		16			
	f=4 GHz		15			
	f=6 GHz		15			
	f=8 GHz		15			
Reverse Isolation	f=2 GHz	14	17	_	dB	
Output Power @ 1 dB compression	f=0.1 GHz	_	12	_	dBm	≥ 1.33
•	f=1 GHz	_	12	_		
	f=2 GHz	10	12	_		
	f=3 GHz	_	12	_		
	f=4 GHz	_	12	_		
	f=6 GHz	_	10.5	_		
	f=8 GHz		8	_		
Saturated Output Power	f=0.1 GHz		13		dBm	
(at 3dB compression)	f=2 GHz		13			
	f=4 GHz		12.5			
	f=6 GHz		11			
	f=8 GHz	0.4	10		dD	. 4.00
Output IP3	f=0.1 GHz	24 24	28	_	dBm	≥ 1.33
	f=1 GHz f=2 GHz	24 23	28 28			
	f=4 GHz	23	28 25	_		
	f=0.1 GHz		4.3	5	dB	≥ 1.33
Noise Figure	f=2 GHz	_	4.3	5.3	l ub	≥ 1.33
	f=4 GHz	_	4.5	5.5		
	f=6 GHz	_	4.5	5.5 —		
	f=8 GHz	_	5.5	_		
Group Delay	f=2 GHz		70		psec	
Recommended Device Operating Current	1-2 (1) 12		40		mA	
Device Operating Voltage		3.2	3.4	3.6	V	≥ 1.5
Device Voltage Variation vs. Temperature at 40mA		0.2	-2.0	0.0	mV/°C	≥ 1.3
Device Voltage Variation vs. Temperature at 40mA Device Voltage Variation vs. Current at 25°C			9.4		mV/mA	
Device voltage variation vs. Cultent at 25 C			5.4	I	III V/IIIA	l

^{*}Guaranteed specification DC-8 GHz. Low frequency cut off determined by external coupling capacitors.

Absolute Maximum Ratings

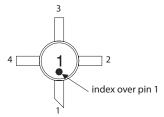
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Parameter	Ratings
Operating Temperature*	-45°C to 85°C
Storage Temperature	-65°C to 150°C
Operating Current	75mA
Power Dissipation	330mW
Input Power	15dBm

Note: Permanent damage may occur if any of these limits are exceeded.

These ratings are not intended for continuous normal operation.
'Case is defined as ground leads.

*Based on typical case temperature rise 5°C above ambient.

Product Marking



Markings in addition to model number designation may appear for internal quality control purposes.

Additional Detailed Technical Information

Additional information is available on our web site. To access this information enter the model number on our web site home page.

Performance data, graphs, s-parameter data set (.zip file)

Case Style: VV105

Plastic micro-x, .085 body diameter, lead finish: matte-tin

Tape & Reel: F4

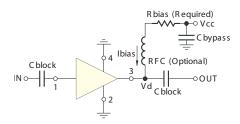
7" Reels with 20, 50, 100, 200, 500, 1K devices

Suggested Layout for PCB Design: PL-261

Evaluation Board: TB-431-1+

Environmental Ratings: ENV08T2

Recommended Application Circuit



Test Board includes case, connectors, and components (in bold) soldered to PCB

R BIAS				
Vcc	"1%" Res. Values (ohms) for Optimum Biasing			
7	90.9			
8	113			
9	137			
10	162			
11	187			
12	215			
13	237			
14	261			
15	287			
16	309			
17	332			
18	357			
19	383			
20	412			

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ESD Rating

Human Body Model (HBM): Class 1B (500 v to < 1,000 v) in accordance with ANSI/ESD STM 5.1 - 2001

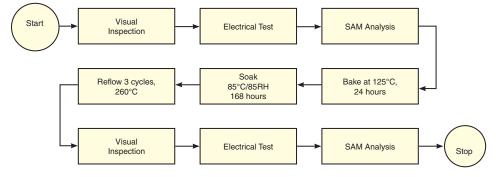
Machine Model (MM): Class M1 (< 100 v) in accordance with ESD STM 5.2 - 1999

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020C

No.	Test Required	Condition	Standard	Quantity
1	Visual Inspection	Low Power Microscope Magnification 40x	MIP-IN-0003 (MCT spec)	45 units
2	Electrical Test	Room Temperature	SCD (MCL spec)	45 units
3	SAM Analysis	Less than 10% growth in term of delamination	J-Std-020C (Jedec Standard)	45 units
4	Moisture Sensitivity Level 1	Bake at 125°C for 24 hours Soak at 85°C/85%RH for 168 hours Reflow 3 cycles at 260°C peak	J-Std-020C (Jedec Standard)	45 units

MSL Test Flow Chart



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